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FAN156 Low Voltage Comparator

Features

- Low Supply Current: I_{DD} 6 μA (Typical)
- Single Power Supply Operation
- Wide Common-Mode Input Voltage Range
- Push-Pull Output Circuit
- Low Input Bias Current
- Internal Hysteresis
- Packaged in MicroPak™ 6

Applications

- Mobile Phones
- Alarm and Security Systems
- Personal Digital Assistants

Description

The FAN156 is a low-power single comparator that typically consumes less than 10 µA of supply current. It is guaranteed to operate at a low voltage of 1.6 V and is fully operational up to 5.5 V, making it convenient for use in 1.8, 3.0 V, and 5.0 V systems.

The FAN156 has a complementary push-pull P- and Nchannel output stage capable of driving a rail-to-rail output swing with a load ranging up to 5.0 mA.

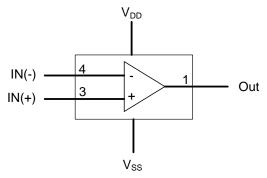


Figure 1. Functional Diagram

Ordering Information

| Part Number | Top Mark | Operating Temperature Range | Package | Packing Method |
|-------------|-------------|--------------------------------|-------------------------------------|--------------------------------|
| FAN156L6X | CN | -40 to 85°C | 6-Lead, MicroPak™, 1 x 1.45 mm Wide | 5000 Units on Tape and Reel |

Pin Configuration

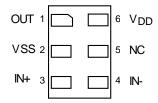


Figure 2. Pin Configuration (Top-Through View)

Pin Definitions

| Pin# | Name | Description | | |
|------|-----------------|-------------------------|--|--|
| 1 | OUT | Comparator Output | | |
| 2 | V _{SS} | ative Supply Voltage | | |
| 3 | IN+ | on-Inverting Input | | |
| 4 | IN- | Inverting Input | | |
| 5 | NC | o Connect | | |
| 6 | V_{DD} | Positive Supply Voltage | | |

Function Table

| Inputs | Outputs | | |
|---------------|-------------|--|--|
| IN(-) > IN(+) | Output LOW | | |
| IN(+) > IN(-) | Output HIGH | | |

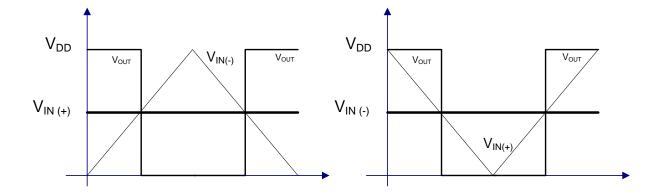


Figure 3. V_{IN} vs. V_{OUT}

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol | Parameter | Condition | Min. | Max. | Unit |
|------------------|--|--|------|----------------------|------|
| Van to Van | Supply Voltage | | -3.0 | +3.0 | V |
| V DD IO V SS | Supply Voltage | | 0 | 6.0 | V |
| DV _{IN} | Differential Input Voltage | | | ±6 | |
| V _{IN} | Input Voltage | | | V_{SS} to V_{DD} | V |
| ts | Output Short Circuit Duration ⁽¹⁾ | | | Indefinite | S |
| TJ | Junction Temperature | | | +150 | °C |
| T _{STG} | Storage Temperature Range | | -65 | +150 | °C |
| P_D | Pow er Dissipation | | | 194 | mW |
| ΘЈА | Thermal Resistance | | | 335 | °C/W |
| | IFC 64000 4.3 System FSD | Air Gap | | 15 | |
| | IEC 61000-4-2 System ESD | Contact | | 8 | |
| | IEDEC IECDOO A444 Lhurrage Dade | All Pins | | 8 | |
| ESD | JEDEC JESD22-A114, Human Body Model | Pin to Pin: IN(-), IN(+) to V _{DD} or VSS | | 12 | kV |
| | JEDEC JESD22-C101, Charged Device Model | All Pins | | 2 | |

Note:

1. The maximum total power dissipation must not be exceeded.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to Absolute Maximum Ratings.

| Symbol | Parameter | Condition | Min. | Max. | Unit |
|------------------------------------|---------------------------------|-----------------------|-------|----------------------|------|
| V _{DD} to V _{SS} | Pow er Supply | | -2.75 | +2.75 | V |
| V DD 10 V 55 | Tower Supply | | 0 | 5.50 | V |
| V _{DD} | Pow er Supply | V _{SS} 0 V | 1.6 | 5.5 | V |
| V _{IN} | Input Voltage | | | V_{SS} to V_{DD} | V |
| | | V _{DD} 5.0 V | | 5 | |
| I_{OH}/I_{OL} | Output Sink/Source Current | V _{DD} 3.0 V | | 3 | mA |
| | | V _{DD} 1.6 V | | 1 | |
| T _A | Operating Temperature, Free Air | | -40 | +85 | °C |

Electrical Characteristics

| Symbol | Parameter | Condition | Min. | Тур. | Max. | Unit |
|--|-------------------------------------|---|----------|------|----------|------|
| V _{DD} =5.5V, V _S | s=GND, and T _A =+25°C | | <u> </u> | | <u> </u> | |
| V _{HYS} | Input Hysteresis | V _{CM} =0.5 V _{DD} | | 4 | | mV |
| V _{IO} | Input Offset Voltage ⁽²⁾ | V _{CM} =0.5 V _{DD} | -15 | ±1 | +15 | mV |
| lio | Input Offset Current | | | 10 | | рА |
| lı | Input Bias Current | | | 10 | | рА |
| V _{CM} | Common Mode Input Voltage | | Vss | | V_{DD} | V |
| CMRR | Common Mode Rejection Ratio (3) | V _{CM} =V _{DD} | | 68 | | dB |
| l _{DD} | Supply Current | | | 6 | 17 | μA |
| PSRR | Pow er Supply Rejection Ratio (3) | $\Delta V_{DD}=0.5 V$ | 45 | 80 | | dB |
| | | V _O =V _{DD} | | 60 | | |
| los | Output Short Circuit Current | V _O =V _{SS} | | 90 | | mA |
| V _{OL} | Low-Level Output Voltage | I _{SINK} =5.0 mA | | 0.1 | 0.3 | V |
| V _{OH} | High-Level Output Voltage | Isource=5.0 mA | 5.2 | 5.4 | | V |
| tpLH | Propagation Delay (Turn-On) | Overdrive 20 mV, C _L =15 pF | | 0.40 | | μs |
| t _{PHL} | Propagation Delay (Turn-Off) | Overdrive=20 mV, C _L =15 pF | | 0.42 | | μs |
| t_{TLH} Response Time, Output Rise/Fall ⁽⁴⁾ | | C _L =50 pF | | 4.0 | | ns |
| | | | | 5.4 | | |
| DD=3V, V _{SS} = | -GND, and T _A =+25°C | | • | | | |
| V_{HYS} | Input Hysteresis | V _{CM} =0.5 V _{DD} | | 4 | | mV |
| V _{IO} | Input Offset Voltage(2) | V _{CM} =0.5 V _{DD} | -15 | ±1 | +15 | mV |
| I _{IO} | Input Offset Current | | | 10 | | pА |
| lı | Input Bias Current | | | 10 | 1 | pА |
| V _{CM} | Common Mode Input Voltage | | Vss | | V_{DD} | V |
| CMRR | Common Mode Rejection Ratio (3) | V _{CM} =V _{DD} | | 60 | | dB |
| l _{DD} | Supply Current | | | 5.5 | 15.0 | μΑ |
| PSRR | Pow er Supply Rejection Ratio (3) | ΔV_{DD} =0.5 V | 45 | 80 | 1 | dB |
| I | Output Short Circuit Current | V _O =V _{DD} | | 27 | | mΛ |
| los | Output Short Circuit Current | Vo=Vss | | 35 | | - mA |
| V _{OL} | Low -Level Output Voltage | I _{SINK} =3.0 mA | | 0.15 | 0.35 | V |
| VoH | High-Level Output Voltage | Isource=3.0 mA | 2.65 | 2.85 | | V |
| t _{PLH} | Propagation Delay (Turn-On) | Overdrive=20 mV, C _L =15 pF | | 0.45 | | μs |
| t _{PHL} | Propagation Delay (Turn-Off) | Overdrive=20 mV, C _L =15 pF | | 0.47 | | μs |
| t⊤∟н | D | 0.50-5 | 1 | 6.1 | 1 | |
| Response Time, Output Rise/Fall ⁽⁴⁾ | | C _L =50pF | | 6.2 | 1 | ns |

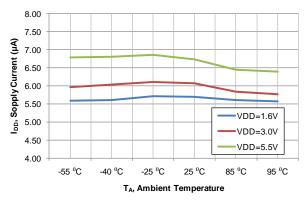
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Electrical Characteristics (Continued)

| Symbol | Parameter | Condition | Min. | Тур. | Max. | Unit | |
|--|-------------------------------------|---|-----------------|------|----------|------|--|
| V _{DD} 1.6V, V _S | S GND, and T _A =+25°C | • | | | | | |
| V _{HYS} | Input Hysteresis | V _{CM} =0.5 V _{DD} | | 3.5 | | mV | |
| V _{IO} | Input Offset Voltage ⁽²⁾ | V _{CM} =0.5 V _{DD} | -15 | ±1 | +15 | mV | |
| lio | Input Offset Current | | | 10 | | pА | |
| lı | Input Bias Current | | | 10 | | pА | |
| V _{CM} | Common Mode Input Voltage | | V _{SS} | | V_{DD} | V | |
| CMRR | Common Mode Rejection Ratio (3) | V _{CM} =V _{DD} | | 56 | | dB | |
| l _{DD} | Supply Current | | | 5 | 15 | μΑ | |
| PSRR | Pow er Supply Rejection Ratio (3) | $\Delta V_{DD}=0.5 V$ | 45 | 80 | | dB | |
| I | Outrot Chart Chart Comment | V _O =V _{DD} | | 5.5 | | mA | |
| los | Output Short Circuit Current | V _O =V _{SS} | | 7.5 | | | |
| V _{OL} | Low -Level Output Voltage | I _{SINK} =1.0 mA | | 0.10 | 0.25 | V | |
| V _{OH} | High-Level Output Voltage | Isource=1.0 mA | 1.35 | 1.50 | | V | |
| t _{PLH} | Propagation Delay (Turn-On) | Overdrive=20 Mv, C _L =15pF | | 0.52 | | μs | |
| t _{PHL} | Propagation Delay (Turn-Off) | Overdrive=20 Mv, C _L =15 pF | | 0.54 | | μs | |
| t _{TLH} | December 7 Time Output Disc/Fall(4) | 0 50 5 | | 16.5 | | | |
| Response Time, Output Rise/Fall ⁽⁴⁾ | | C _L =50 pF | | 13.0 | | ns | |

- Differential input switching level is guaranteed at the minimum or maximum offset voltage, minus or plus half the maximum hysteresis voltage.
- Guaranteed by design and characterization data.
- 4. Input signal: 1 kHz, square-wave signal with 10 ns edge rate.

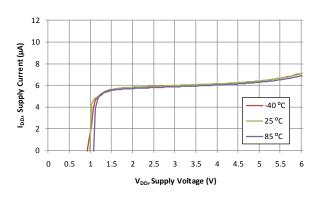
Typical Performance Characteristics



900 800 1.6 VDD 700 600 3.0 VDD ξĒ 5.5 VDD 500 <u>පු</u> 400 300 200 100 0.01 Temp. =25C 10 100 1000 Frequency (Khz) C_L = 15pF

Figure 4. Supply Current vs. Temperature

Figure 5. Supply Current vs. Output Transition Frequency



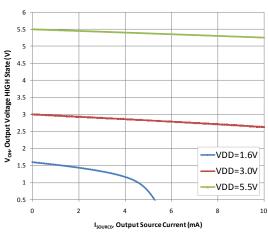
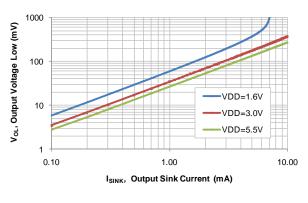


Figure 6. Supply Current vs. Supply Voltage

Figure 7. Output HIGH vs. Output Drive Current



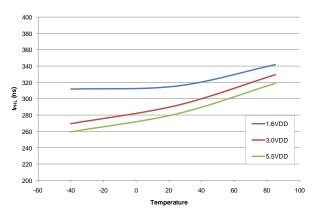
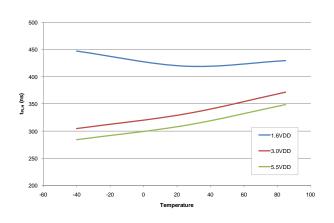


Figure 8. Output LOW vs. Output Drive Current

Figure 9. Propagation Delay (tPHL) vs. Temperature

Typical Performance Characteristics (Continued)



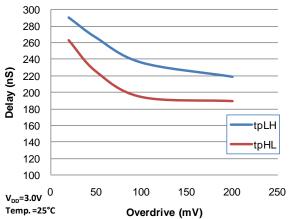
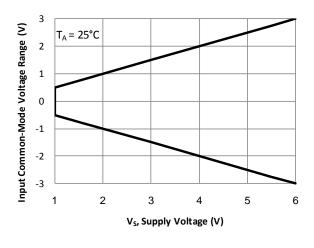


Figure 10. Propagation Delay (tPLH) vs. Temperature





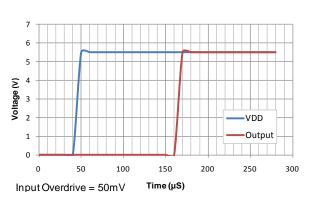
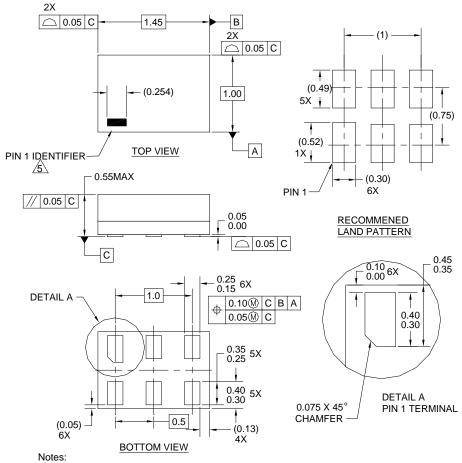


Figure 12. Input Common-Mode Voltage Range vs. Supply Voltage

Figure 13. Power-Up Delay

Physical Dimensions



- 1. CONFORMS TO JEDEC STANDARD M0-252 VARIATION UAAD
- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y14.5M-1994 4. FILENAME AND REVISION: MAC06AREV4
- 5. PIN ONE IDENTIFIER IS 2X LENGTH OF ANY

OTHER LINE IN THE MARK CODE LAYOUT.

Figure 14. 6-Lead, MicroPak™, 1 x 1.45 mm Wide

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| Package Designator | Tape Section | Cavity Number | Cavity Status | Cover Type Status |
|--------------------|--------------------|---------------|---------------|-------------------|
| | Leader (Start End) | 125 (Typical) | Empty | Sealed |
| L6X | Carrier | 5000 | Filled | Sealed |
| | Trailer (Hub End) | 75 (Typical) | Empty | Sealed |

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